

DS25CP152

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SNLS274D – JANUARY 2008 – REVISED APRIL 2013

DS25CP152 3.125 Gbps LVDS 2x2 Crosspoint Switch

Check for Samples: DS25CP152

FEATURES

- DC 3.125 Gbps Low Jitter, Low Skew, Low Power Operation
- Pin Configurable, Fully Differential, Non-Blocking Architecture
- On-Chip 100Ω Input and Output Terminations Minimize Return Losses, Reduce Component Count and Minimize Board Space
- 8 kV ESD on LVDS I/O Pins Protects Adjoining Components
- Small 4 mm x 4 mm WQFN-16 Space Saving Package

APPLICATIONS

- High-Speed Channel select Applications
- Clock and Data Buffering and Muxing
- OC-48 / STM-16
- SD/HD/3G HD SDI Routers

Typical Application

DESCRIPTION

The DS25CP152 is a 3.125 Gbps 2x2 LVDS crosspoint switch optimized for high-speed signal routing and switching over lossy FR-4 printed circuit board backplanes and balanced cables. Fully differential signal paths ensure exceptional signal integrity and noise immunity. The non-blocking architecture allows connections of any input to any output or outputs.

Wide input common mode range allows the switch to accept signals with LVDS, CML and LVPECL levels; the output levels are LVDS. A very small package footprint requires a minimal space on the board while the flow-through pinout allows easy board layout. Each differential input and output is internally terminated with a 100Ω resistor to lower device return losses, reduce component count and further minimize board space.

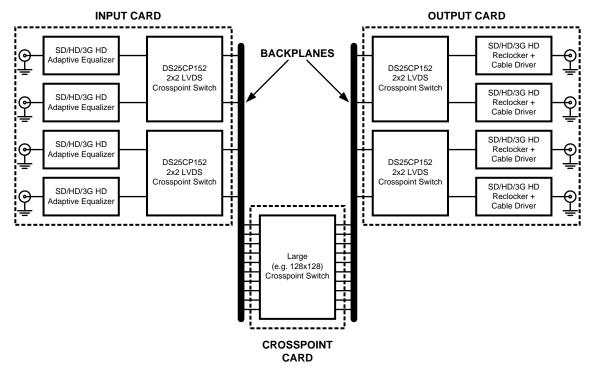


Figure 1. Typical Application

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Block Diagram

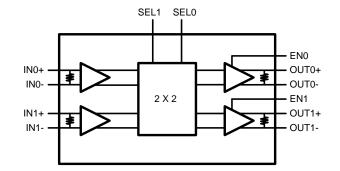
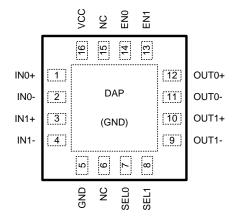


Figure 2. Block Diagram

Connection Diagram





PIN DESCRIPTIONS

Pin Name	Pin Number	I/O, Туре	Pin Description		
IN0+, IN0- , IN1+, IN1-	1, 2, 3, 4	I, LVDS	Inverting and non-inverting high speed LVDS input pins.		
OUT0+, OUT0-, OUT1+, OUT1-	12, 11, 10, 9	O, LVDS	Inverting and non-inverting high speed LVDS output pins.		
SEL0, SEL1	7, 8	I, LVCMOS	Switch configuration pins. There is a 20 k Ω pulldown resistor on each pin.		
EN0, EN1	14, 13	I, LVCMOS	Output enable pins. There is a 20 k Ω pulldown resistor on each pin.		
NC	6, 15	I, LVCMOS	"NO CONNECT" pins.		
VDD	16	Power	Power supply pin.		
GND	5, DAP	Power	Ground pin and Device Attach Pad (DAP) ground.		



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings⁽¹⁾⁽²⁾

Absolute maximum Natings	
Supply Voltage	-0.3V to +4V
LVCMOS Input Voltage	-0.3V to (V _{CC} + 0.3V)
LVDS Input Voltage	-0.3V to +4V
Differential Input Voltage VID	1.0V
LVDS Output Voltage	-0.3V to (V _{CC} + 0.3V)
LVDS Differential Output Voltage	0V to 1.0V
LVDS Output Short Circuit Current Duration	5 ms
Junction Temperature	+150°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature Range	
Soldering (4 sec.)	+260°C
Maximum Package Power Dissipation at 25°C	
RGH0016A Package	2.99W
Derate RGH0016A Package	23.9 mW/°C above +25°C
Package Thermal Resistance	
θ _{JA}	+41.8°C/W
θ _{JC}	+6.9°C/W
ESD Susceptibility	
HBM ⁽³⁾	≥8 kV
MM ⁽⁴⁾	≥250V
CDM ⁽⁵⁾	≥1250V

(1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions.

(2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.

(3) Human Body Model, applicable std. JESD22-A114C

(4) Machine Model, applicable std. JESD22-A115-A

(5) Field Induced Charge Device Model, applicable std. JESD22-C101-C

Recommended Operating Conditions

	Min	Тур	Max	Units
Supply Voltage (V _{CC})	3.0	3.3	3.6	V
Receiver Differential Input Voltage (VID)	0		1	V
Operating Free Air Temperature (T _A)	-40	+25	+85	°C

DC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified.^{(1) (2) (3)}

Symbol	Parameter	Conditions	Min	Тур	Max	Units
LVCMOS	S DC SPECIFICATIONS		·			
V _{IH}	High Level Input Voltage		2.0		V _{CC}	V
VIL	Low Level Input Voltage		GND		0.8	V
I _{IH}	High Level Input Current	V _{IN} = 3.6V V _{CC} = 3.6V	40	175	250	μA
IIL	Low Level Input Current	$V_{IN} = GND$ $V_{CC} = 3.6V$		0	±10	μA

(1) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.

(2) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V_{OD} and ΔV_{OD}.

(3) Typical values represent most likely parametric norms for $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

STRUMENTS

XAS

DC Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified.^{(1) (2) (3)}

Symbol	Parameter	Conditions	Min	Тур	Max −1.5	Units	
V _{CL}	Input Clamp Voltage	$I_{CL} = -18 \text{ mA}, V_{CC} = 0 \text{V}$		-0.9		V	
LVDS IN	IPUT DC SPECIFICATIONS					*	
V _{ID}	Input Differential Voltage		0		1	V	
V _{TH}	Differential Input High Threshold	V_{CM} = +0.05V or V_{CC} -0.05V		0	+100	mV	
V _{TL}	Differential Input Low Threshold		-100	0		mV	
V _{CMR}	Common Mode Voltage Range	V _{ID} = 100 mV	0.05		V _{CC} - 0.05	V	
I _{IN}	Input Current	V _{IN} = +3.6V or 0V V _{CC} = 3.6V or 0V		±1	±10	μA	
C _{IN}	Input Capacitance	Any LVDS Input Pin to GND		1.7		pF	
R _{IN}	Input Termination Resistor	Between IN+ and IN-		100		Ω	
LVDS O	UTPUT DC SPECIFICATIONS						
V _{OD}	Differential Output Voltage		250	350	450	mV	
ΔV_{OD}	Change in Magnitude of V _{OD} for Complimentary Output States	$R_L = 100\Omega$	-35		35	mV	
V _{OS}	Offset Voltage		1.05	1.2	1.375	V	
ΔV _{OS}	Change in Magnitude of V _{OS} for Complimentary Output States	R _L = 100Ω	-35		35	mV	
l _{os}	Output Short Circuit Current ⁽⁴⁾	OUT to GND		-35	-55	mA	
		OUT to V _{CC}		7	55	mA	
C _{OUT}	Output Capacitance	Any LVDS Output Pin to GND		1.2		pF	
R _{OUT}	Output Termination Resistor	Between OUT+ and OUT-		100		Ω	
	CURRENT	·					
I _{CC}	Supply Current	EN0 = EN1 = High		64	77	mA	
I _{CCZ}	Supply Current with Outputs Disabled	EN0 = EN1 = Low		23	29	mA	

(4) Output short circuit current (I_{OS}) is specified as magnitude only, minus sign indicates direction only.

AC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified ^{(1) (2)}

Symbol	Parameter	Conditions	Min	Тур	Max	Units
LVDS OUTPUT A	C SPECIFICATIONS					
t _{PLHD}	Differential Propagation Delay Low to High $^{\rm (3)}$	D 1000		340	500	ps
t _{PHLD}	Differential Propagation Delay High to Low $^{\rm (3)}$	$R_{L} = 100\Omega$		344	500	ps
t _{SKD1}	Pulse Skew t _{PLHD} - t _{PHLD}			4	35	ps
t _{SKD2}	Channel to Channel Skew			12	40	ps
t _{SKD3}	Part to Part Skew			50	150	ps

(1) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or notes. Typical specifications are estimations only and are not ensured.

(2) Typical values represent most likely parametric norms for $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.

(3) Specification is ensured by characterization and is not tested in production.

(4) t_{SKD1}, |t_{PLHD} - t_{PHLD}], Pulse Skew, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.

(5) t_{SKD2}, Channel to Channel Skew, is the difference in propagation delay (t_{PLHD} or t_{PHLD}) among all output channels in Broadcast mode (any one input to all outputs).

(6) t_{SKD3} , Part to Part Skew, is defined as the difference between the minimum and maximum differential propagation delays. This specification applies to devices at the same V_{CC} and within 5°C of each other within the operating temperature range.



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AC Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified ^{(1) (2)}

Symbol	Parameter	Conditions		Min	Тур	Max	Units
t _{LHT}	Rise Time ⁽³⁾	D 4000			65	120	ps
t _{HLT}	Fall Time ⁽³⁾	$R_L = 100\Omega$			65	120	ps
t _{ON}	Output Enable Time	ENn = LH to output	active		7	20	μs
t _{OFF}	Output Disable Time	ENn = HL to output	ENn = HL to output inactive			12	ns
t _{SEL}	Select Time	SELn LH or HL to o		3.5	12	ns	
JITTER PERFO	RMANCE ⁽³⁾						
t _{RJ1}	Random Jitter (RMS Value)	V _{ID} = 350 mV	2.5 Gbps		0.5	1	ps
t _{RJ2}	(7)	V _{CM} = 1.2V Clock (RZ)	3.125 Gbps		0.5	1	ps
t _{DJ1}	Deterministic Jitter (Peak to Peak)	V _{ID} = 350 mV	2.5 Gbps		8	25	ps
t _{DJ2}	(8)	V _{CM} = 1.2V K28.5 (NRZ)	3.125 Gbps		3	19	ps
t _{TJ1}	Total Jitter (Peak to Peak)	V _{ID} = 350 mV	2.5 Gbps		0.04	0.08	UI _{P-P}
t _{TJ2}	(9)	V _{CM} = 1.2V PRBS-23 (NRZ)	3.125 Gbps		0.03	0.09	UI _{P-P}

(7) Measured on a clock edge with a histogram and an accumulation of 1500 histogram hits. Input stimulus jitter is subtracted geometrically.

(8) Tested with a combination of the 1100000101 (K28.5+ character) and 0011111010 (K28.5- character) patterns. Input stimulus jitter is subtracted algebraically.

(9) Measured on an eye diagram with a histogram and an accumulation of 3500 histogram hits. Input stimulus jitter is subtracted.

DC Test Circuits

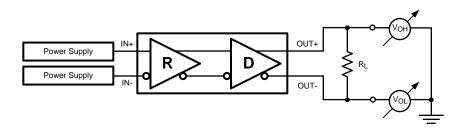


Figure 4. Differential Driver DC Test Circuit

AC Test Circuits and Timing Diagrams

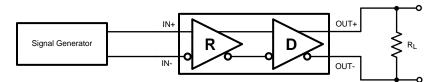
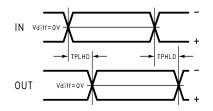


Figure 5. Differential Driver AC Test Circuit







IN1

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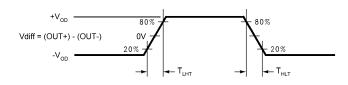


Figure 7. LVDS Output Transition Times

Functional Description

1

The DS25CP152 is a 3.125 Gbps 2x2 LVDS digital crosspoint switch optimized for high-speed signal routing and switching over lossy FR-4 printed circuit board backplanes and balanced cables.

S1	SO	OUT1	OUT0
0	0	INO	IN0
0	1	INO	IN1
1	0	IN1	IN0

1

Table 1. Switch Configuration Truth Table

Table 2. Output Enable Truth Table

IN1

EN1	EN0	OUT1	OUT0
0	0	Disabled	Disabled
0	1	Disabled	Enabled
1	0	Enabled	Disabled
1	1	Enabled	Enabled

Input Interfacing

The DS25CP152 accepts differential signals and allows simple AC or DC coupling. With a wide common mode range, the DS25CP152 can be DC-coupled with all common differential drivers (i.e. LVPECL, LVDS, CML). The following three figures illustrate typical DC-coupled interface to common differential drivers. Note that the DS25CP152 inputs are internally terminated with a 100Ω resistor.

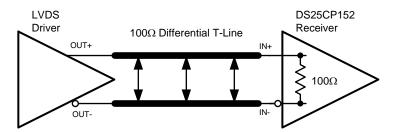
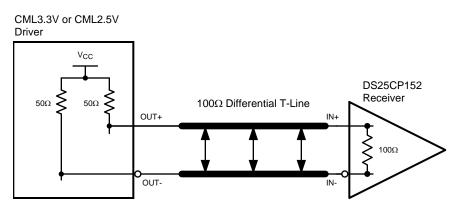


Figure 8. Typical LVDS Driver DC-Coupled Interface to DS25CP152 Input



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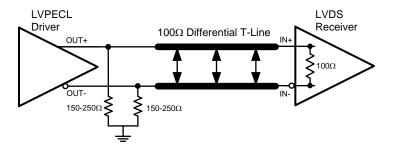
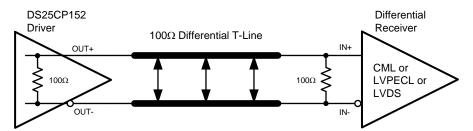


Figure 10. Typical LVPECL Driver DC-Coupled Interface to DS25CP152 Input

Output Interfacing

The DS25CP152 outputs signals that are compliant to the LVDS standard. Its outputs can be DC-coupled to most common differential receivers. The following figure illustrates typical DC-coupled interface to common differential receivers and assumes that the receivers have high impedance inputs. While most differential receivers have a common mode input range that can accommodate LVDS compliant signals, it is recommended to check the respective receiver's data sheet prior to implementing the suggested interface implementation.





Typical Performance Characteristics

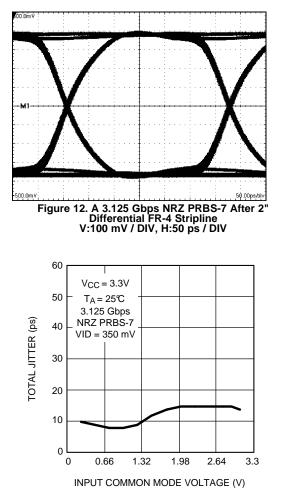
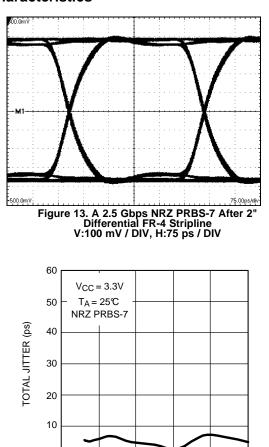


Figure 14. Total Jitter as a Function of Input Common Mode Voltage



DATA RATE (Gbps) Figure 15. Total Jitter as a Function of Data Rate

1.6

2.4

4.0

3.2

0

0

0.8

Page



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Changes from	Revision C	(April 201	3) to Revisi	on D
Changes nom	VENI2IOU C	201 × (April 201	3) IU KEVISI	

•	Changed layout of National Data Sheet to TI format	8



15-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
DS25CP152TSQ/NOPB	ACTIVE	WQFN	RGH	16	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	2C152SQ	Samples
DS25CP152TSQX/NOPB	ACTIVE	WQFN	RGH	16	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	2C152SQ	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS25CP152TSQ/NOPB	WQFN	RGH	16	1000	178.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
DS25CP152TSQX/NOPB	WQFN	RGH	16	4500	330.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

11-Oct-2013



*All dimensions are nominal

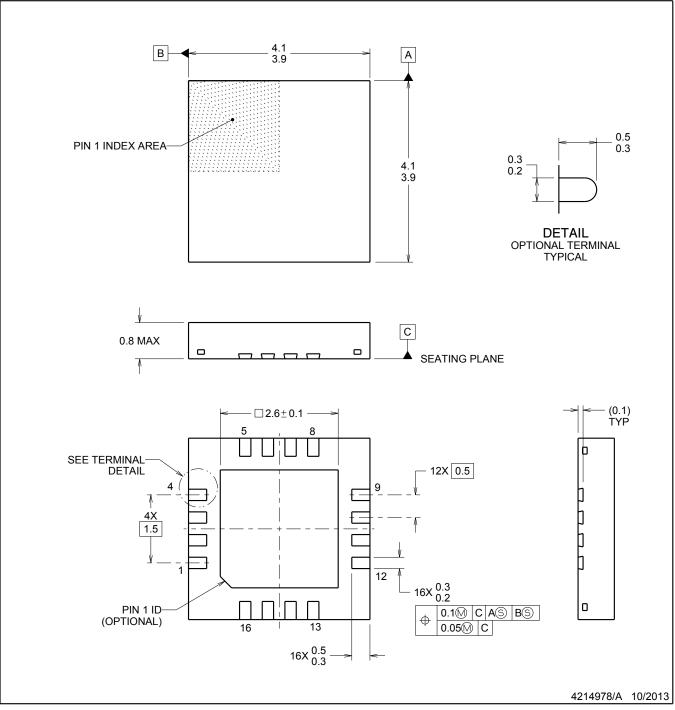
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS25CP152TSQ/NOPB	WQFN	RGH	16	1000	210.0	185.0	35.0
DS25CP152TSQX/NOPB	WQFN	RGH	16	4500	367.0	367.0	35.0

PACKAGE OUTLINE

RGH0016A

WQFN - 0.8 mm max height

WQFN



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

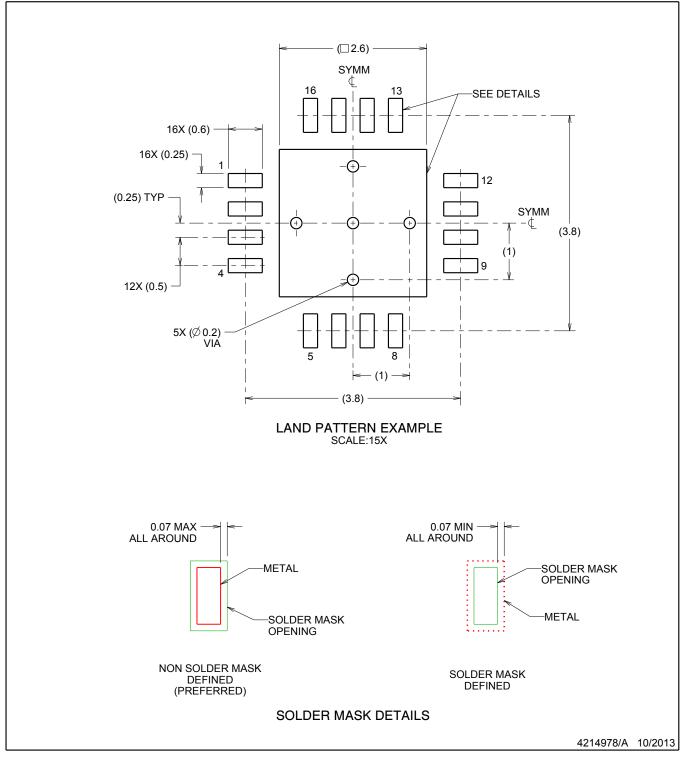


RGH0016A

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

WQFN



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).

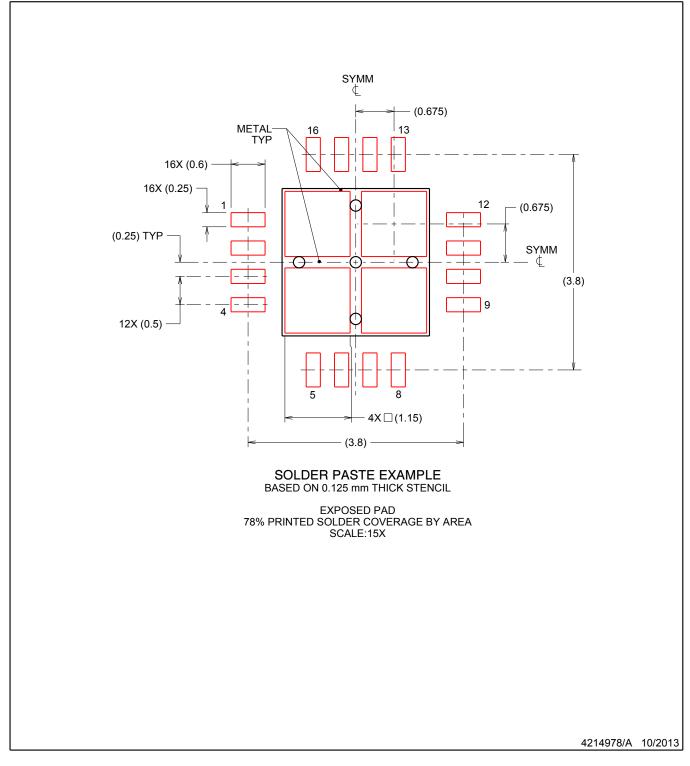


RGH0016A

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

WQFN



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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